## Notice of References Cited

Application/Control No. 10/733,431	Applicant(s)/Pater Reexamination BERNE ET AL.	nt Under
Examiner	Art Unit	_
Evan Pert	2826	Page 1 of 1

## U.S. PATENT DOCUMENTS

*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Name	Classification
	Α	US-6,632,724 B2	10-2003	Henley et al.	438/455
	В	US-6,828,216 B2	12-2004	Schwarzenbach et al.	438/458
	С	US-6,838,358 B2	01-2005	Maurice et al.	438/458
	D	US-			
	E	US-			
	F	US-			
	G	US-			
	Н	US-			
	1	US-			
	J	US-			
	к	US-			
	L	US-		`	
	м	US-			

## FOREIGN PATENT DOCUMENTS

*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Country	Name	Classification
	N					
	0					
	Р					
	Q					
	R					
	s					
	Т					

## **NON-PATENT DOCUMENTS**

*		Include as applicable: Author, Title Date, Publisher, Edition or Volume, Pertinent Pages)
	U	A.J. Auberton-Herve, "SOI: Materials to Systems," 1996 IEEE IEDM, pages 3-10.
	٧	Q.Y. Tong et al., "Low Temperature Si Layer Splitting," October 1997, Proceedings of the 1997 IEEE International SOI Conference, pages 126-127.
	w	U. Gosele, "Semiconductor wafer bonding: A flexible approach to materials combinations in microelectronics; micromechanics and optoelectronics," October 1997, IEEE CAS '97 Proceedings, vol. 1, pages 23-32.
	х	

\*A copy of this reference is not being furnished with this Office action. (See MPEP § 707.05(a).)

Dates in MM-YYYY format are publication dates. Classifications may be US or foreign.